





DK Seminar

October 21, 2015, 13:30 - 15:00 Vienna University of Technology, Freihaus, green area, 4th floor, 101C

Polina Shpartko

Vienna University of Technology

Possibility of consideration of energy transport in spin-polarized model for semiconductors

Spin of an electron as an additional degree of freedom to the electrons charge could be used to transport and store information in microelectronic devices. My previous work concerned spin-polarized drift-diffusion model describing transport of spin in semiconductors. In the talk I will present several models which except of charge and spin transport incorporate also the transport of energy. I will explain the origin of these models, discuss their physical validity and share the ideas about their solvability.